

GSBT2036

PHASE CONTROLLED SCR

Stud-box assembly

VOLTAGE UP TO 1600 V
AVERAGE CURRENT 360 A
SURGE CURRENT 8.5 kA

BLOCKING CHARACTERISTICS

Characteristic	Conditions	Value
VRRM	Repetitive peak reverse voltage	1600 V
VRSM	Non-repetitive peak reverse voltage	1700 V
VDRM	Repetitive peak off-state voltage	1600 V
IDRM	Repetitive peak off-state current, max.	VDRM, single phase, half wave, T _j = T _{jmax}
I _{RRM}	Repetitive peak reverse current, max.	VRRM, single phase, half wave, T _j = T _{jmax}

ON-STATE CHARACTERISTICS

I _{T(AV)}	Average on-state current	Sine wave, 180° conduction, Th = 55 °C	360 A
I _{T(RMS)}	R.M.S. on-state current	Sine wave, 180° conduction, Th = 55 °C	565 A
I _{TSM}	Surge on-state current	Non rep. half sine wave, 50 Hz, V _R = 0 V, T _j = T _{jmax}	8.5 kA
I ² t	I ² t for fusing coordination		361 kA ² s
V _{T(TO)}	Threshold voltage	T _j = T _{jmax}	0.90 V
r _T	On-state slope resistance	T _j = T _{jmax}	0.650 mΩ
V _{TM}	Peak on-state voltage, max	On-state current I _T = 1000 A, T _j = 25 °C	1.62 V
I _H	Holding current, max	T _j = 25 °C	600 mA
I _L	Latching current, typ	T _j = 25 °C	1000 mA

TRIGGERING CHARACTERISTICS

V _{GT}	Gate trigger voltage	T _j = 25 °C, V _D = 5 V	3.0 V
I _{GT}	Gate trigger current	T _j = 25 °C, V _D = 5 V	200 mA
V _{GD}	Non-trigger voltage	V _D = 67% VRRM, T _j = T _{jmax}	0.25 V
P _{GM}	Peak gate power dissipation	Pulse width 5 ms	10 W
P _{G(AV)}	Average gate power dissipation		2 W
I _{FGM}	Peak gate current		3 A
V _{FGM}	Peak gate voltage (forward)		20 V
V _{RGM}	Peak gate voltage (reverse)		5 V

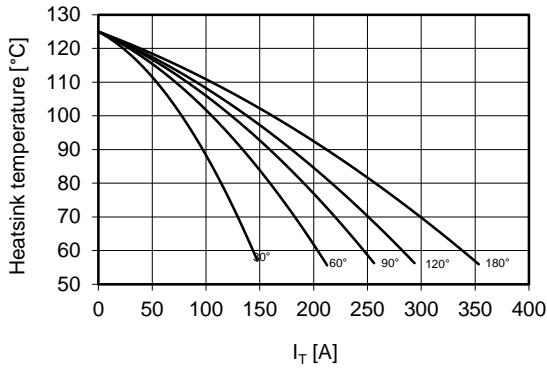
SWITCHING CHARACTERISTICS

di/dt	Critical rate of rise of on-state current	T _j = T _{jmax}	200 A/μs
dV/dt	Critical rate of rise of off-state voltage	T _j = T _{jmax}	500 V/μs
t _q	Turn-off time, typ	T _j = T _{jmax} , I _T = 320 A, di/dt = -12.5 A/μs VR = 100 V, VD = 67% VDRM, dV/dt = 20 V/μs	μs

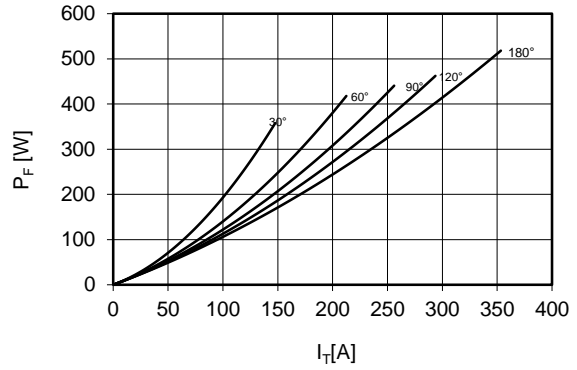
THERMAL AND MECHANICAL CHARACTERISTICS

R _{th(j-c)}	Thermal resistance (junction to case)		0.12 °C/W
R _{th(c-h)}	Thermal resistance (case to heatsink)		0.01 °C/W
T _{jmax}	Max operating junction temperature		125 °C
T _{stg}	Storage temperature		-40 / 125 °C
M	Mounting torque ± 10%	Non lubricated threads	31.0 N·m
	Mass		600 g

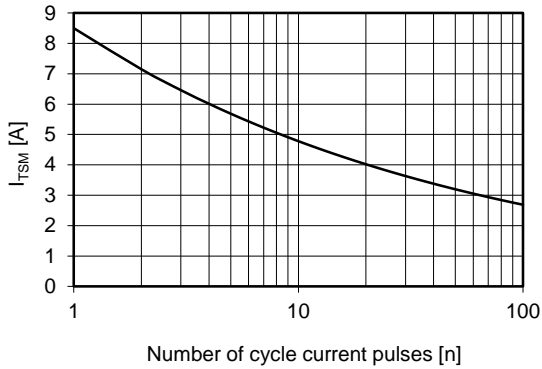
Current rating - sine wave



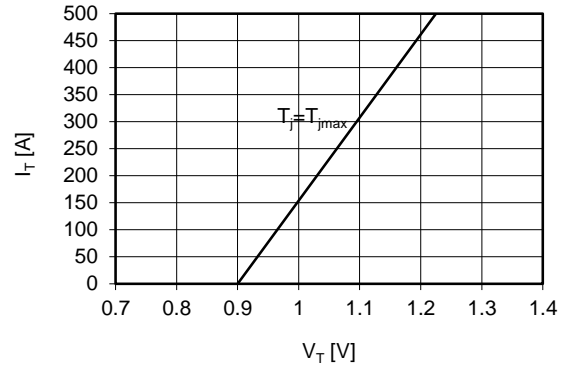
Power loss - sine wave



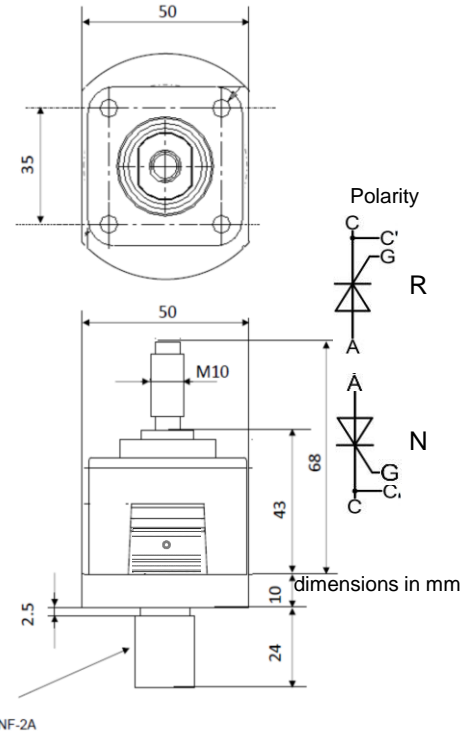
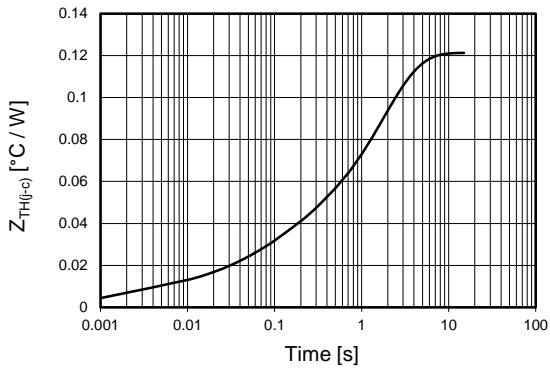
Maximum surge current d.s. cooled



On-state voltage drop



Thermal impedance (j-c)



Ordering information GSBT2036-VVGLP-TEEH-XX

- VV**: blocking voltage / 100 (e.g. 16 for 1600 V)
- G**: trigger lead type (**S** = straight **T** = twisted **blank** = no leads)
- L**: trigger lead length x 100 mm (**3 - 4 - 5 - 7 blank** = no leads)
- P**: polarity: **N** = cathode to base (black) - **R** = anode to base (red)
- T**: cross sectional area of the braid **3** = 35 mm² - **4** = 42 mm² - **5** = 50 mm²
- EE**: length of the pgtail (center hole-center hole) in mm / 10
- H**: lug eyelet hole for screw **6** = M6 - **8** = M8 - **1** = M10
- XX**: Custom variation (blank = standard)

In the interest of product improvement Green Power Solutions reserves the right to change any specification given in this data sheet without notice.